SAC3004

GaAs MMIC Low Noise Amplifier
0.2～2.6GHz

Rev 2.2

Features

- Frequency：0.2GHz～2.6GHz
- Gain：21dB
- Output P_{-1}dB：20.5dBm
- Supply Voltage：+5V@90mA
- Die Size：1.3mm×1.25mm×0.1mm

Typical Applications

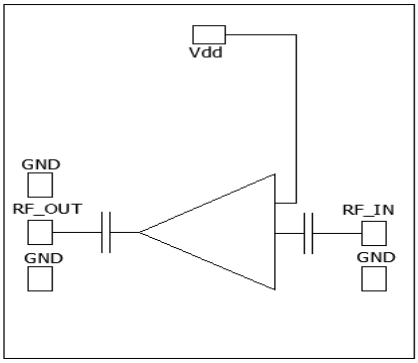
- Radar and ECM
- RF/ Microwave radio
- Military and Space
- Test and Measurement
- Fiber Optics

General Description

SAC3004 is a GaAs MMIC Low Noise Amplifier die which operates between 0.2GHz～2.6GHz. The amplifier can provide 21dB gain, 20.5dBm OutputP_{-1}dB,less than 3dB noise figure from a 90mA supply current.

The chip offers full passivation for increased reliability and moisture protection. This amplifier is the perfect alternative to higher cost hybrid amplifiers.

Functional Diagram



Electrical Performance (T_A=25℃, V_D=+5V, I_D=90mA, Z_O=50Ω)

Parameter	Min.	Typ.	Max.	Units
Frequency Range		0.2～2.6		GHz
Gain	—	21	—	dB
Gain Flatness	—	5.5	—	dB
Reverse Isolation	—	-25	—	dB
Input/Output VSWR	—	1.8	—	:1
Noise Figure	—	1.3	—	dB
Output Power for 1 dB Compression (OP_{-1}dB)	—	20.5	—	dBm
Output Third Order Intercept (OIP_3)	—	31	—	dBm
Supply Current(I_D)	—	90	—	mA

Absolute Maximum Ratings

Maximum Input Power	+18dBm	Operating Temperature	-55℃～+85℃
Channel Temperature	+150℃	Storage Temperature	-65℃～+150℃

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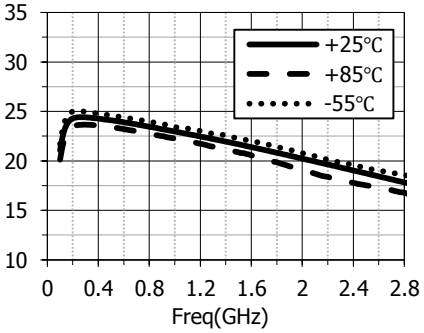
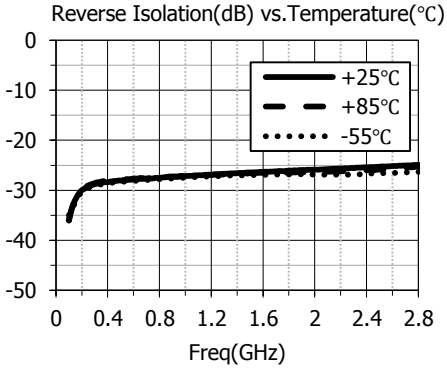
Typical Performance Curve

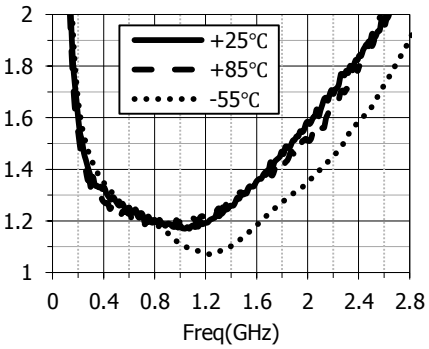
Gain (dB)vs.Temperature(℃)



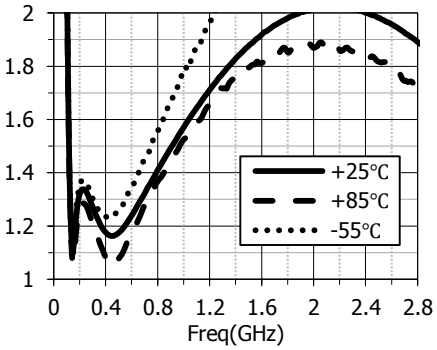
Reverse Isolation(dB) vs.Temperature(℃)



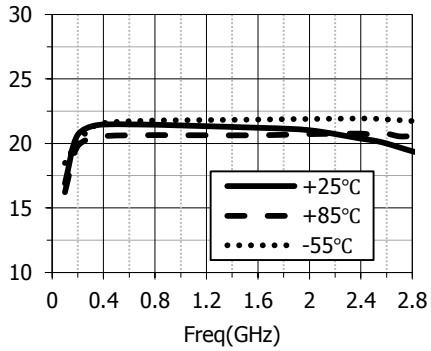
Input VSWR(:1) vs.Temperature(℃)



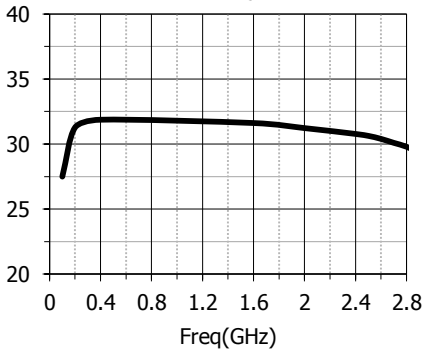
Output VSWR(:1) vs.Temperature(℃)



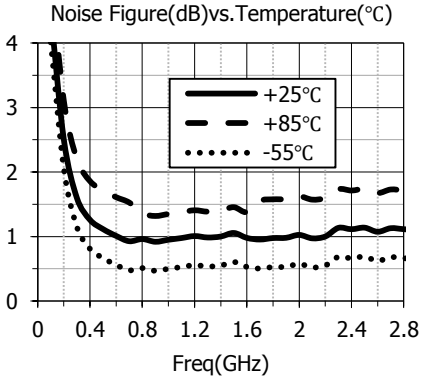
Output P_{-1}dB(dBm) vs.Temperature(℃)



Output IP_3(dBm)

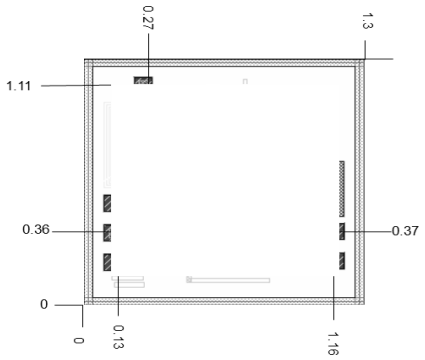


Noise Figure(dB)vs.Temperature(℃)

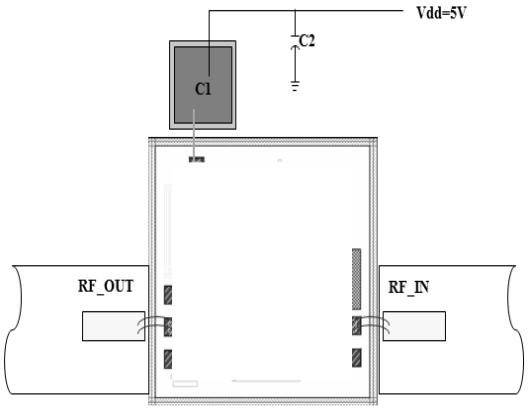


Die Outline

(All dimensions in mm)



Assembly Diagram



Components List

Reference Des.	Value	Part Number	Manuf.	Size
C1	300pF	—	RADVISTA	Chip
C2	10nF	GRM155R71H103KA88D	MURATA	0402

Attention:

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.